

20A, 100V - 200V Schottky Barrier Surface Mount Rectifier

FEATURES

- AEC-Q101 qualified
- Low power loss, high efficiency
- Ideal for automated placement
- Guard ring for overvoltage protection
- High surge current capability
- Moisture sensitivity level: level 1, per J-STD-020
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

APPLICATIONS

- Low voltage, high freq. inverter
- DC/DC converter
- Freewheeling diodes
- Reverse battery protection
- Car lighting

MECHANICAL DATA

- Case: TO-263AB (D²PAK)
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 2 whisker test
- Polarity: As marked
- Weight: 1.40g (approximately)

KEY PARAMETERS			
PARAMETER	VALUE	UNIT	
I _F	20	Α	
V_{RRM}	100 - 200 V		
I _{FSM}	150 A		
T _{J MAX}	175 °C		
Package	TO-263AB (D ² PAK)		
Configuration	Dual dies		

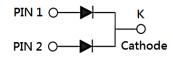








TO-263AB (D²PAK)



ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)					
PARAMETER	SYMBOL	MBRS 20H100CT	MBRS 20H150CT	MBRS 20H200CT	UNIT
		Н	Н	н	
Marking code on the device		MBRS 20H100CT	MBRS 20H150CT	MBRS 20H200CT	
Repetitive peak reverse voltage	V_{RRM}	100	150	200	V
Reverse voltage, total rms value	$V_{R(RMS)}$	70	105	140	V
Forward current	I _F	20			Α
Surge peak forward current, 8.3ms single half sine wave superimposed on rated load	I _{FSM}	150			А
Peak repetitive forward current (Rated V _R , Square wave, 20KHz)	I _{FRM}	20		Α	
Peak repetitive reverse surge current ⁽¹⁾	I _{RRM}	1 0.5		Α	
Critical rate of rise of off-state voltage	dv/dt	10,000		V/µs	
Junction temperature	TJ	-55 to +175		°C	
Storage temperature	T _{STG}	-55 to +175		°C	

Notes

1. $tp = 2.0\mu s$, 1.0KHz



MBRS20H100CTH - MBRS20H200CTH

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THERMAL PERFORMANCE			
PARAMETER	SYMBOL	TYP	UNIT
Junction-to-case thermal resistance	$R_{\Theta JC}$	1.5	°C/W

ELECTRICAL SPECIFICATIONS (T _A = 25°C unless otherwise noted)						
PARAMETER		CONDITIONS	SYMBOL	TYP	MAX	UNIT
	MBRS20H100CTH	I _F = 10A, T _J = 25°C		-	0.85	V
	MBRS20H150CTH MBRS20H200CTH			-	0.88	V
	MBRS20H100CTH			-	0.95	V
Forward voltage	MBRS20H150CTH MBRS20H200CTH	$I_F = 20A, T_J = 25^{\circ}C$	V _F	-	0.97	V
per diode (1)	MBRS20H100CTH	I _F = 10A, T _J = 125°C	۷F	-	0.75	V
	MBRS20H150CTH MBRS20H200CTH			-	0.75	V
	MBRS20H100CTH	I _F = 20A, T _J = 125°C		-	0.85	V
	MBRS20H150CTH MBRS20H200CTH			-	0.85	V
Reverse current @ rated V _R per diode ⁽²⁾		T _J = 25°C	- I _R	-	5	μA
		T _J = 125°C		-	2	mA

Notes:

- 1. Pulse test with PW = 0.3ms
- 2. Pulse test with PW = 30ms

ORDERING INFORMATION			
ORDERING CODE ⁽¹⁾	PACKAGE	PACKING	
MBRS20HxCTH	TO-263AB (D ² PAK)	800 / Tape & Reel	

Notes:

1. "x" defines voltage from 100V(MBRS20H100CTH) to 200V(MBRS20H200CTH)



CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

Fig.1 Forward Current Derating Curve

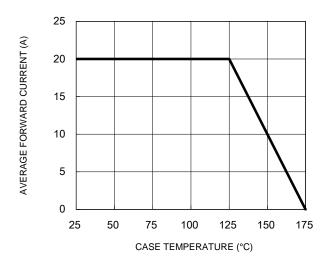


Fig.2 Typical Junction Capacitance

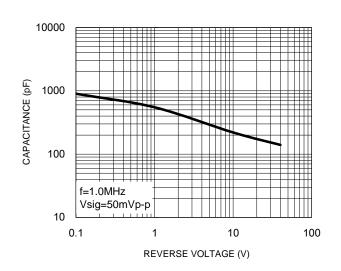
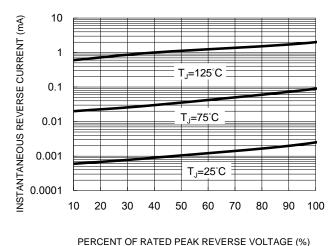
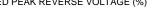


Fig.3 Typical Reverse Characteristics

Fig.4 Typical Forward Characteristics





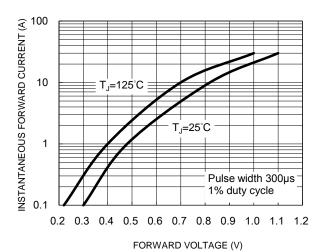
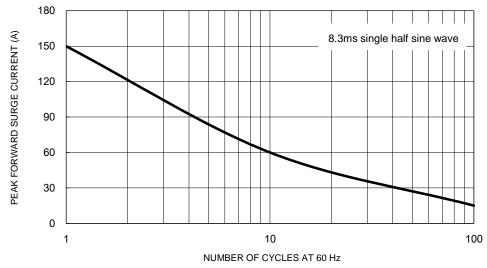


Fig.5 Maximum Non-Repetitive Forward Surge Current



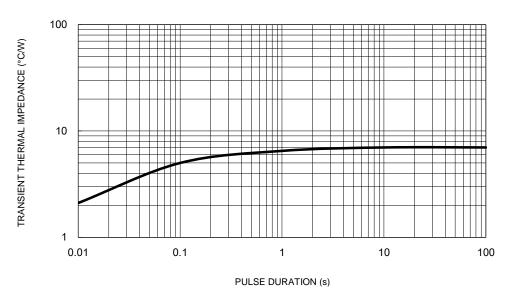
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CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

Fig.6 Typical Transient Thermal Impedance

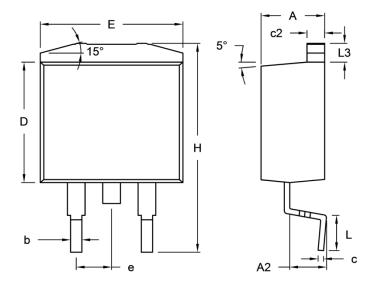




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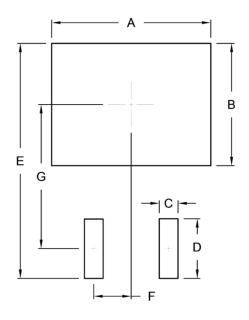
PACKAGE OUTLINE DIMENSIONS

TO-263AB (D²PAK)



DIM.	Unit (mm)		Unit (inch)	
DIW.	Min.	Min. Max.		Max.	
Α	4.44	4.70	0.175	0.185	
A2	2.03	2.79	0.080	0.110	
b	0.68	0.94	0.027	0.037	
С	0.36	0.53	0.014	0.021	
c2	1.14	1.40	0.045	0.055	
D	8.25	9.25	0.325	0.364	
Е	-	10.50	-	0.413	
е	2.41	2.67	0.095	0.105	
Н	14.60	15.88	0.575	0.625	
L	2.29	2.79	0.090	0.110	
L3	1.14	1.40	0.045	0.055	

SUGGESTED PAD LAYOUT



Symbol	Unit (mm)	Unit (inch)
Α	10.80	0.425
В	8.30	0.327
С	1.27	0.050
D	4.05	0.159
E	15.95	0.628
F	2.54	0.100
G	9.775	0.385

MARKING DIAGRAM



P/N = Marking Code G = Green Compound

YWW = Date Code F = Factory Code



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